

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX373F, TC74LCX373FK

Low-Voltage Octal D-Type Latch with 5-V Tolerant Inputs and Outputs

The TC74LCX373 is a high-performance CMOS octal D-type latch. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

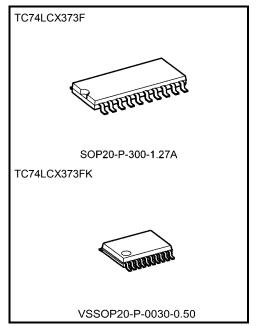
The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 1.65 V to 3.6 V
- High-speed operation: $t_{pd} = 8.0 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: | IOH | /IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: >±500 mA
- Available in JEITA SOP, VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 373 type



Weight

SOP20-P-300-1.27A : 0.22 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Note: The Electrical Characteristics of V_{CC} = 1.8 \pm 0.15 V is only applicable for products which manufactured from January 2009 onward.

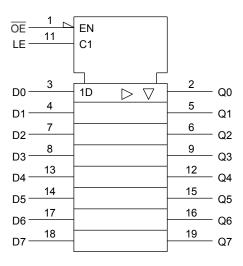
Start of commercial production 1994-10



Pin Assignment (top view)

$\overline{\mathsf{OE}}$ 20 Vcc Q0 Q7 2 19 D0 3 D7 18 D1 D6 Q1 Q6 Q2 6 Q5 D2 7 D5 D3 8 D4 Q3 Q4 GND 10 LE

IEC Logic Symbol



Truth Table

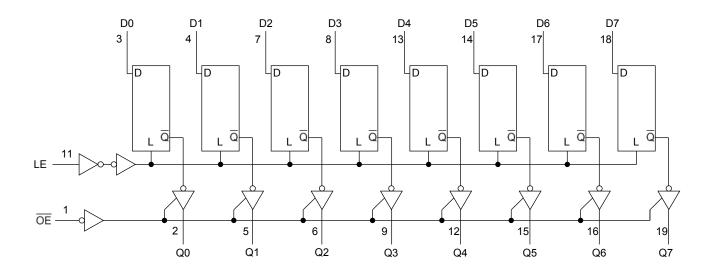
	Outputo		
ŌĒ	LE	D	Outputs
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _C C	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lık	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC Vcc/ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Dower aupply voltage	Voc	1.65 to 3.6	
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V
Input voltage	VIN	0 to 5.5	V
Output voltage	Vout	0 to 5.5 (Note 3)	V
Output voltage		0 to V _{CC} (Note 4)	V
Output ourront	lou/lou	±24 (Note 5)	mA
Output current	IOH/IOL	±12 (Note 6)	IIIA
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Curahal	Took Co.	a diki a a		NAim	Max	l lmit	
Characteris	SUCS	Symbol	Test Co	Test Condition		Min		Unit	
					1.65 to2.3	V _{CC} × 0.9	_		
H-level		VIH	_	_		1.7	_		
Input voltage					2.7 to 3.6	2.0	_	V	
					1.65 to2.3	_	Vcc × 0.1	V	
	L-level	VIL	_	-	2.3 to2.7	_	0.7		
					2.7 to 3.6		0.8		
				$I_{OH} = -100 \mu A$	1.65 to 3.6	V _{CC} - 0.2			
				IOH = -4 mA	1.65	1.05	_		
	H-level	Vон	VIN = VIH or VIL	I _{OH} = -8 mA	2.3	1.7	_	V	
				$I_{OH} = -12 \text{ mA}$	2.7	2.2	_		
				I _{OH} = -18 mA	3.0	2.4	_		
Output valtage				I _{OH} = -24 mA	3.0	2.2	_		
Output voltage	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 100 \mu A$	1.65 to 3.6		0.2		
				$I_{OL} = 4 \text{ mA}$	1.65	_	0.45		
				I _{OL} = 8 mA	2.3	_	0.7		
	L-level			I _{OL} = 12 mA	2.7	_	0.4		
				I _{OL} = 16 mA	3.0		0.4		
				I _{OL} = 24 mA	3.0		0.55		
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		1.65 to 3.6		±5.0	μΑ	
3-state output OFF state current		loz	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μА	
Power-off leakage curr	ent	loff	$V_{IN}/V_{OUT} = 5.5 V$		0	_	10.0	μА	
Order count countries to		loo	VIN = VCC or GND		1.65 to 3.6		10.0		
Quiescent supply curre	#11L	Icc	V _{IN} /V _{OUT} = 3.6 to 5.5 V		1.65 to 3.6	_	±10.0	μΑ	
Increase in ICC per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 V_{IH}$	(per 1 input)	2.7 to 3.6	_	500		



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
			1.8 ± 0.15	_	30.0	
Propagation delay time	tpLH		2.5 ± 0.2	_	10.0	ns
(D-Q)	tpHL	Figure 1, Figure 2	2.7	_	9.0	
			3.3 ± 0.3	1.5	8.0	
			1.8 ± 0.15	_	30.0	
Propagation delay time	t _{pLH}	E: 4 E: 0	2.5 ± 0.2	_	10.5	
(LE-Q)	t _{pHL}	Figure 1, Figure 2	2.7	_	9.5	ns
			3.3 ± 0.3	1.5	8.5	
			1.8 ± 0.15	_	34.0	
Outroit analys time	t _{pZL}	Figure 4 Figure 2	2.5 ± 0.2	_	17.0	ns
Output enable time	t _{pZH}	Figure 1, Figure 3	2.7	_	9.5	
			3.3 ± 0.3	1.5	8.5	
	t _P LZ t _P HZ		1.8 ± 0.15	_	32.0	
Output disable time		Figure 1, Figure 3	2.5 ± 0.2	_	16.0	ns
			2.7	_	8.5	
			3.3 ± 0.3	1.5	7.5	
	t _w (H)	Figure 1, Figure 2	1.8 ± 0.15	12.0	_	ns
Minimum pulse width			2.5 ± 0.2	6.0		
(LE)			2.7	4.0	_	
			3.3 ± 0.3	3.3	_	
			1.8 ± 0.15	10.0	_	
			2.5 ± 0.2	5.0	_	- ns
Minimum setup time	ts	Figure 1, Figure 2	2.7	2.5	_	
			3.3 ± 0.3	2.5	_	
		Figure 1, Figure 2	1.8 ± 0.15	1.5	_	
Minimum hold time	4.		2.5 ± 0.2	1.5	_	ns
	th		2.7	1.5		
			3.3 ± 0.3	1.5		
Output to output skew	t _{osLH}	(Note)	2.7	_	_	ne
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	ns

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

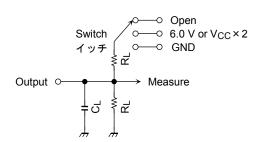
Characteristics	Symbol	Test Condition		Vcc (V)	Тур.	Unit
Input capacitance	CIN	_		3.3	7	pF
Output capacitance	Cout	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	ote)	3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/8 (per bit)$

AC Test Circuit



Parameter		Switch		
t _{pLH} , t _{pHL}	Open			
	6.0 V	@ V _{CC} =3.3±0.3V @ V _{CC} =2.7V		
t _{pLZ} , t _{pZL}	V _{CC} ×2	@ V _{CC} =2.5±0.2V @ V _{CC} =1.8±0.15V		
t _{pHZ} , t _{pZH}	GND			

Figure 1



AC Waveform

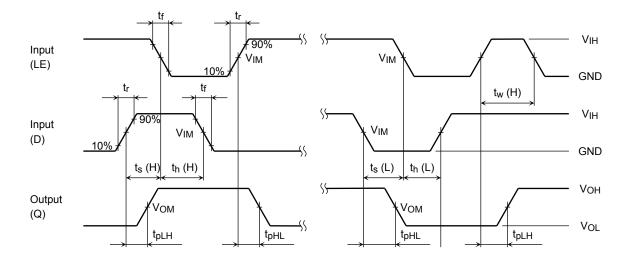


Figure 2 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

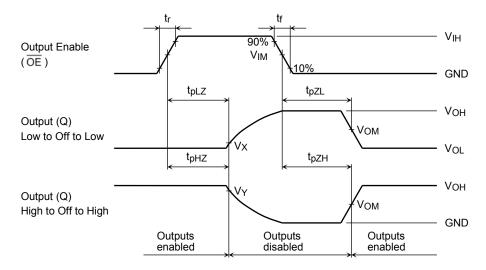


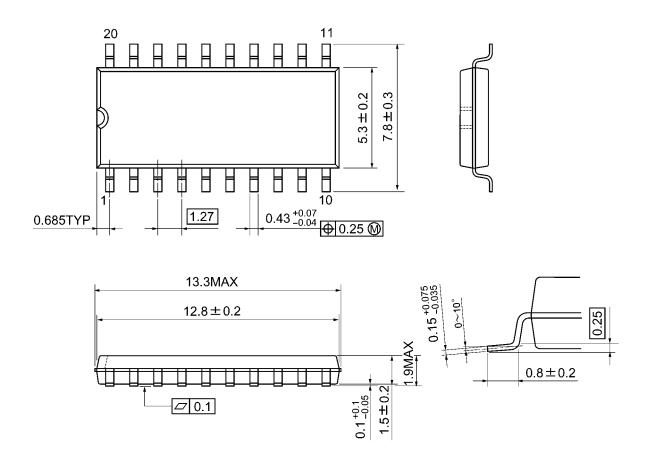
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

		Vcc					
	Symbol	$3.3 \pm 0.3 \text{ V}$ 2.7 V	$2.5\pm0.2\textrm{V}$	1.8 ± 0.15 V			
Input	VIH	2.7 V	Vcc	Vcc			
	VIM	1.5 V	V _{CC} /2	V _{CC} /2			
	t _r , t _f	2.5 ns	2.0 ns	2.0 ns			
Output	Vом	1.5 V	V _{OH} /2	V _{OH} /2			
	VX	V _{OL} +0.3 V	V _{OL} +0.15 V	V _{OL} +0.15 V			
	VY	V _{OH} -0.3 V	V _{OH} -0.15 V	V _{OH} -0.15 V			
Load	CL	50 pF	30 pF	30 pF			
	RL	500 Ω	500 Ω	1 kΩ			



Package Dimensions

SOP20-P-300-1.27A Unit: mm

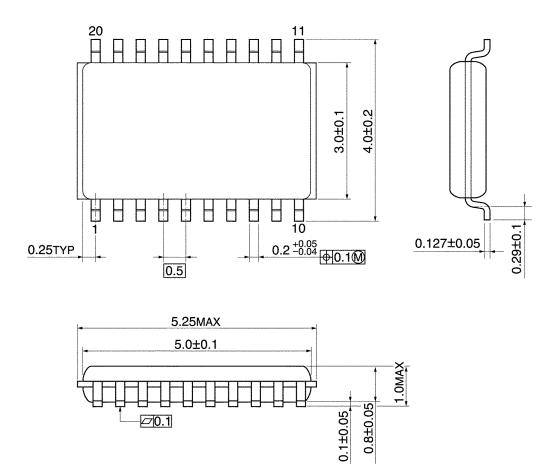


Weight: 0.22 g (typ.)



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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